

## Silicon Medium Barrier Schottky Diodes

M/A-COM Products Rev. V10

#### **Features**

- RF & Microwave Medium Barrier Silicon 20 V Schottky Diode
- Available as Single Diode, Series Pair or Unconnected Pair Configurations.
- Low Profile Surface Mount Plastic Packages
- Lead Free (RoHS Compliant) Equivalents Available With 260 Deg. C Reflow Capability

### **Description and Applications**

The MA4E1339 series is a silicon medium barrier Schottky diode suitable for use in mixer, detector and limiter circuits. These diodes are also usable in anti-parallel, shunt power surge protection circuits for 50  $\Omega$  and 75  $\Omega$  systems.

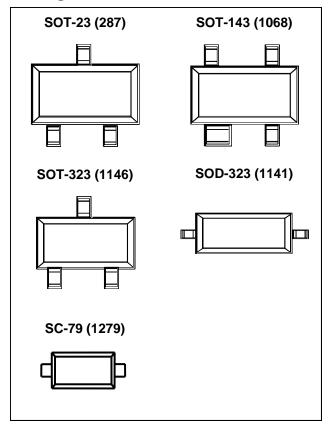
These parts are offered with Sn/Pb plating, as well as with 100 % matte Sn plating on the RoHS compliant part numbers.

The MA4E1339 Series of Schottky diodes is available in the SOT-23 ( case style 287 ), SOT-143 ( case style 1068 ), SOT-323 ( case style 1146 ), SOD 323 (case style 1141) and the SC-79 (case style 1279).

These packages are supplied on tape and reel for automatic pick and place assembly and for surface mount placement to circuit boards, as indicated by a "T" to the P/N suffix.

These Silicon Medium Barrier, 20 V Schottky Diodes are Useful in Detector, Limiter, Mixer, and Surge Protection Applications for Operating Frequency Bands from D.C. through 6 GHz.

### **Package Outlines**



Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

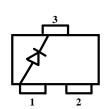
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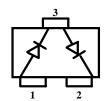
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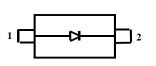
## **Configurations (Top View)**



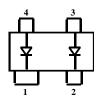
Single MA4E1339A-287T MA4E1339A-1146T



Series Pair MA4E1339B-287T MA4E1339B-1146T



Single MA4E1339A1-1141T MADS-001339-1279OT



Unconnected Pair MA4E1339E-1068T

### **Standard Part Numbers and RoHS Equivalents**

Standard Part Number	RoHS Compliant Part Number	Package Style
MA4E1339A-287T	MA4E1339A1-287T	SOT-23
MA4E1339A-1146T	MA4E1339A1-1146T	SOT-323
MA4E1339B-287T	MA4E1339B1-287T	SOT-23
MA4E1339B-1146T	MA4E1339B1-1146T	SOT-323
N/A	MA4E1339A1-1141T	SOD-323
N/A	MADS-001339-1279OT	SC-79
MA4E1339E-1068T	MA4E1339E1-1068T	SOT-143



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## Maximum Ratings 25 °C (unless otherwise specified)<sup>1</sup>

Parameter	Unit	Values
Operating Temperature	°C	-55 to +125
Storage Temperature	°C	-55 to +125
Total Power Dissipation (RF and D.C.)	mW	250
Continuous Forward Current	mA	30
Surge Forward Current, @ t<10 millisec	mA	100
Reverse Voltage	٧	20
Soldering Temperature (Standard Part #)	°C	+235 for 5 sec. <sup>2</sup>
Soldering Temperature (RoHS Compliant Part #)	°C	+260 for 5 sec. <sup>2</sup>
Electrostatic Discharge ( ESD ) Classification	-	1A

<sup>1.</sup> Operation of this device above any one of the Maximum Rated parameters may cause permanent damage.

# Electrical Specifications @ $T_A = +25$ °C

Parameter	Condition	Şymbol	Specification
Forward Voltage	I <sub>F</sub> = 1 mA	V <sub>F</sub>	410 mV max.
Delta Forward Current	I <sub>F</sub> = 1 mA	V <sub>F</sub>	20 mV max. For series pair and unconnected pair configurations
Forward Voltage	I <sub>F</sub> = 10 mA	V <sub>F</sub>	1.0 V max.
Total Capacitance	V <sub>R</sub> = 0 V F = 1 MHz	Ст	1.2 pF max.
Reverse Leakage Current	V <sub>R</sub> = 15 V	I <sub>R</sub>	200 nA max.
Reverse Voltage Breakdown	I <sub>R</sub> = 10 μA	V <sub>B</sub>	20 V min.

<sup>2.</sup> Please refer to Application Note M538 for surface mounting instructions.

<sup>3.</sup> ESD rating based on Human Body Model.

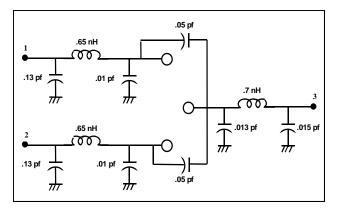


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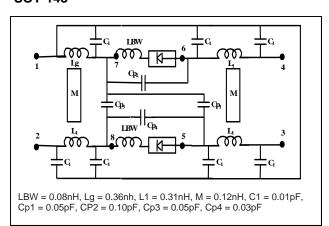
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#### **Circuit Models**

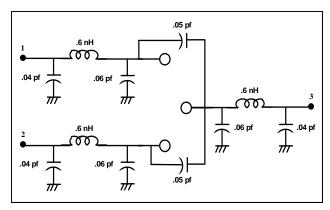
#### **SOT-23**



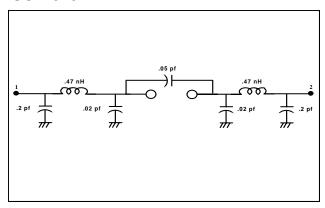
#### **SOT-143**



#### **SOT-323**



### **SOD-323**



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Visit www.macomtech.com for additional data sheets and product information.

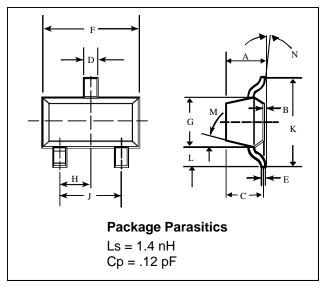


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### **Case Styles**

### **SOT-23**

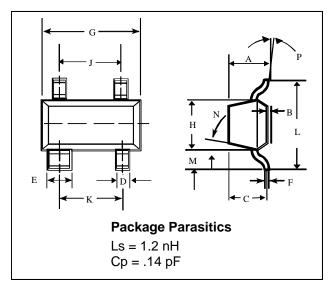


### SOT-23 (Case Style 287)

	INCHES		MILLIM	ETERS
DIM.	MIN.	MAX.	MIN.	MAX.
Α	-	0.048	-	1.22
В	-	0.008	-	0.20
С	=	0.040	-	1.00
D	0.013	0.020	0.35	0.50
Е	0.003	0.006	0.08	0.15
F	0.110	0.119	2.80	3.00
G	0.047	0.056	1.20	1.40
Н	0.037 typical		0.95 t	ypical
J	0.075 typical		1.90 t	ypical
K	-	0.103	-	2.60
L	-	0.024	-	0.60
DIM.	GRADIENT			
M	10° max.3			
N	2°30°			

3. Applicable on all sides

### **SOT-143**



## **SOT-143 (Case Style 1068)**

	INCHES		MILLIM	ETERS
DIM.	MIN.	MAX.	MIN.	MAX.
Α	-	0.044	-	1.10
В	-	0.044	-	1.10
С	-	0.040	-	1.00
D	0.013	0.020	0.35	0.50
E	0.030	0.035	0.75	0.90
F	0.003	0.006	0.08	0.15
G	0.110	0.119	2.80	3.00
Н	0.047	0.056	1.20	1.40
J	0.075 typical		1.90 t	ypical
K	0.075 typical		1.90 t	ypical
L	-	0.103	-	2.6
M	-	0.024	-	0.6
DIM.	GRADIENT			
N	10° max. 4			
Р	2° 30°			

4. Applicable on all sides

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

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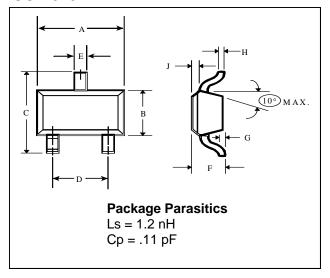


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## **Case Styles**

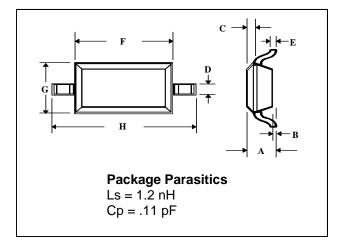
#### **SOT-323**



## **SOT-323 (Case Style 1146)**

	INCHES		MILLIM	ETERS
DIM.	MIN.	MAX.	MIN.	MAX.
Α	0.063	0.087	1.6	2.2
В	0.045	0.053	1.15	1.35
С	0.079	0.087	2.0	2.2
D	0.047	0.055	1.2	1.4
E	0.008	0.016	0.2	0.4
F	0.031	0.039	0.8	1.0
G		0.004	-	0.1
Н	0.003	0.006	0.08	0.15
J	0.004	0.010	0.1	0.25

### **SOD-323**



## **SOD-323 (Case Style 1141)**

	INCHES		MILLIM	ETERS
DIM.	MIN.	MAX.	MIN.	MAX.
Α	-	0.043	=	1.1
В	1	0.004	-	0.1
С	1	0.008	_	0.2
D	0.010	0.016	0.25	0.4
Е	0.003	0.006	0.08	0.15
F	0.063	0.075	1.6	1.9
G	0.045	0.057	1.15	1.45
Н	0.091	0.106	2.3	2.7

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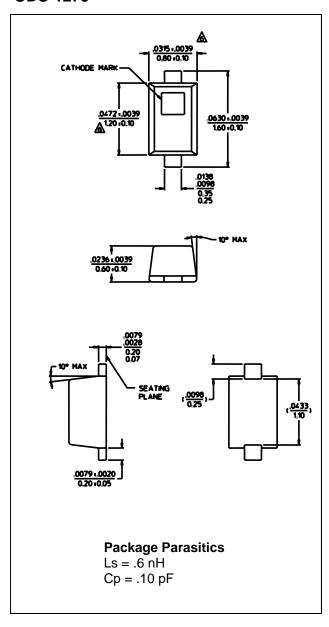


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### **Case Styles**

#### **ODS-1279**



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